AlGaAs Infrared Laser Diode

850nm 50mW 5.6φ TO-Type Laser Diode

Features

Low operation current Cost effective

Applications

Bar-code scanner Laser printer Sensing

Absolute maximum ratings

Parameter	Symbol	Condition	Rating	Unit
Light output power	Po	CW	50	mW
Reverse voltage (LD)	V _{RL}	-	2	V
Reverse voltage (PD)	V _{RD}	-	30	V
Forward current (PD)	I _{FD}	-	10	mA
Case temperature	Tc	-	-10~+50	°C
Storage temperature	Ts	-	-40~+85	°C

Electrical and optical characteristics (T_c=25 °C)

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Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Peak wavelength	λ	840	850	860	nm	P₀=50 mW	
Threshold current	I _{th}	-	25	30	mA		
Operating current	I _{op}	-	95	105	mA		
Operating voltage	V _{op}	-	1.8	2.4	V		
Differential efficiency	η	0.7	0.8	1.0	mW/mA	P _o =10-50 mW	
Monitor current	I _m	0.2	0.5	1.0	mA	P₀=50mW, V _{RD} =5V	
Parallel divergence angle	θ//	6	9	12	deg		
Perpendicular divergence angle	θ_	26	30	35	deg	P _o =50 mW	
Parallel divergence angle	Δ θ//	-3	-	+3	deg		
Perpendicular divergence angle	$\Delta \theta_{\perp}$	-3	-	+3	deg		
Emission point accuracy	Δ xΔ yΔ z	-80	-	+80	um		

• Precautions

Do not operate the device above maximum ratings. Doing so may cause unexpected and permanent damage to the device.

Take precautions to avoid electrostatic discharge and/or momentary power spikes. A change in the characteristics of the laser or premature failure may result.
Proper heat sinking of the device assures stability and lifetime. Always ensure that maximum operating temperatures are not exceeded.

Observing visible or invisible laser beams with the human eye directly, or indirectly, can cause permanent damage. Use a camera to observe the laser.

* No laser device should be used in any application or situation where life or property is at risk in event of device failure.

* Specifications are subject to change without notice. Ensure that you have the latest specification by contacting us prior to purchase or use of the product.

ARIMA LASERS CORP.





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